



#### 30V P-Channel Enhancement Mode MOSFET

Voltage

-30 V

Current

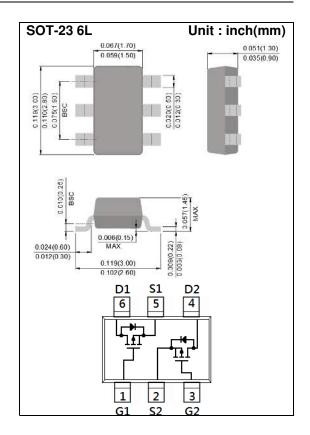
-2.6A

#### **Features**

- RDS(ON), VGS@-10V, ID@-2.6A<115mΩ
- RDS(ON) , VGS@-4.5V, ID@-1.7A<150mΩ</li>
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc.
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

#### **Mechanical Data**

- Case: SOT-23 6L Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0005 ounces, 0.014 grams
- Marking: ST9



## Maximum Ratings and Thermal Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

| PARAMETER  |                      | SYMBOL           | LIMIT       | UNITS |
|--|----------------------|------------------|-------------|-------|
| Drain-Source Voltage   |                      | V <sub>DS</sub>  | -30         | V     |
| Gate-Source Voltage  |                      | V <sub>GS</sub>  | <u>+</u> 20 | V     |
| Continuous Drain Current   |                      | ID               | -2.6        | Α     |
| Pulsed Drain Current   |                      | I <sub>DM</sub>  | -10.4       | Α     |
| Power Dissipation  | T <sub>a</sub> =25°C | P <sub>D</sub>   | 1.25        | W     |
|  | Derate above 25°C    |                  | 10          | mW/°C |
| Operating Junction and Storage Temperature Range                     |                      | $T_{J}, T_{STG}$ | -55~150     | °C    |
| Typical Thermal Resistance - Junction to Ambient <sup>(Note 3)</sup> |                      | ReJA             | 100         | °C/W  |





### Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

| PARAMETER                        | SYMBOL              | TEST CONDITION   | MIN. | TYP.        | MAX.         | UNITS |
|----------------------------------|---------------------|--|------|-------------|--------------|-------|
| Static                           |                     |  |      |             |              |       |
| Drain-Source Breakdown Voltage   | BV <sub>DSS</sub>   | V <sub>GS</sub> =0V, I <sub>D</sub> =-250uA  | -30  | -           | -            | V     |
| Gate Threshold Voltage           | $V_{\text{GS(th)}}$ | V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =-250uA                                    | -1   | -1.31       | -2.1         | V     |
| Drain-Source On-State Resistance | R <sub>DS(on)</sub> | V <sub>GS</sub> =-10V, I <sub>D</sub> =-2.6A   | -    | 93          | 115          | mΩ    |
|                                  |                     | V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-1.7A  | -    | 116         | 150          |       |
| Zero Gate Voltage Drain Current  | IDSS                | V <sub>DS</sub> =-30V, V <sub>GS</sub> =0V   | -    | -0.01       | -1           | uA    |
| Gate-Source Leakage Current      | Igss                | V <sub>GS=±</sub> 20V, V <sub>DS</sub> =0V   | -    | <u>+</u> 10 | <u>+</u> 100 | nA    |
| Dynamic                          |                     |  |      |             |              |       |
| Total Gate Charge                | $Q_g$               | V <sub>DS</sub> =-15V, I <sub>D</sub> =-2.6A,<br>V <sub>GS</sub> =-10V <sup>(Note 1,2)</sup> | -    | 9.8         | -            | nC    |
| Gate-Source Charge               | Qgs                 |  | -    | 1.5         | -            |       |
| Gate-Drain Charge                | $Q_{gd}$            |  | -    | 2.2         | -            |       |
| Input Capacitance                | Ciss                | V <sub>DS</sub> =-15V, V <sub>GS</sub> =0V,  | -    | 396         | -            | pF    |
| Output Capacitance               | Coss                |  | -    | 47          | -            |       |
| Reverse Transfer Capacitance     | Crss                | I=1.UIVITZ   | -    | 36          | -            |       |
| Switching                        |                     |  |      |             |              |       |
| Turn-On Delay Time               | td <sub>(on)</sub>  | $V_{DD}$ =-15V, $I_{D}$ =-2.6A, $V_{GS}$ =-10V, $R_{G}$ =6 $\Omega^{(Note 1,2)}$             | -    | 5           | -            |       |
| Turn-On Rise Time                | tr                  |  | -    | 30          | -            | ns    |
| Turn-Off Delay Time              | td <sub>(off)</sub> |  | -    | 25          | -            |       |
| Turn-Off Fall Time               | tf                  | MG=012(1000 1,2)   | -    | 8           | -            |       |
| Drain-Source Diode               |                     |  |      |             |              |       |
| Maximum Continuous Drain-Source  | Is                  |  |      | -           | -1.5         | Α     |
| Diode Forward Current            | IS                  |  | _    |             |              |       |
| Diode Forward Voltage            | $V_{\text{SD}}$     | I <sub>S</sub> =-1.0A, V <sub>G</sub> S=0V   | -    | -0.77       | -1.2         | ٧     |

#### NOTES:

- 1. Pulse width < 300us, Duty cycle < 2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper
- 4. The maximum current rating is package limited





#### **TYPICAL CHARACTERISTIC CURVES**

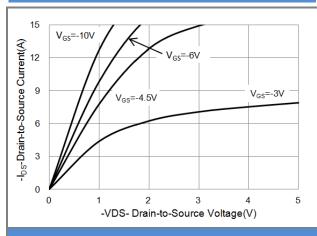


Fig.1 On-Region Characteristics

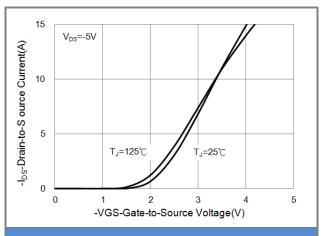


Fig.2 Transfer Characteristics

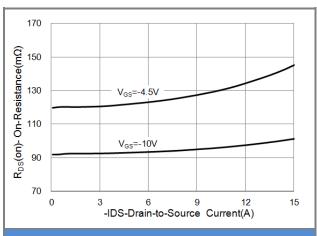


Fig.3 On-Resistance vs. Drain Current

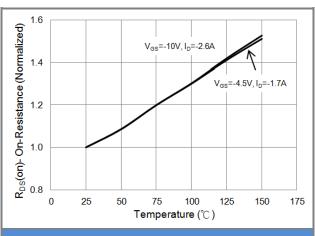
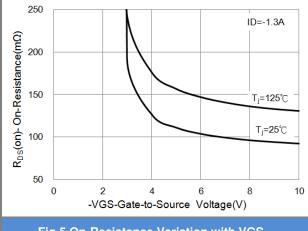
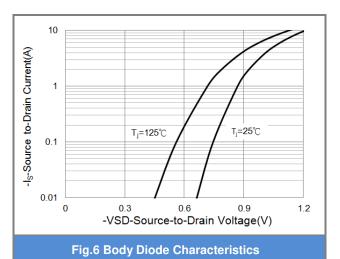


Fig.4 On-Resistance vs. Junction temperature











#### **TYPICAL CHARACTERISTIC CURVES**

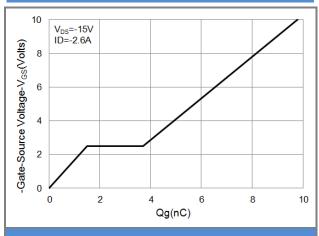


Fig.7 Gate-Charge Characteristics

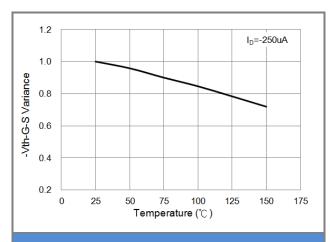


Fig.8 Threshold Voltage Variation with Temperature

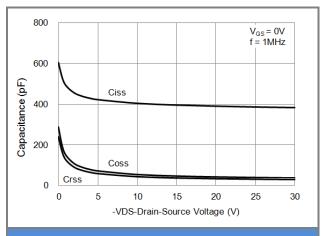


Fig.9 Capacitance vs. Drain-Source Voltage

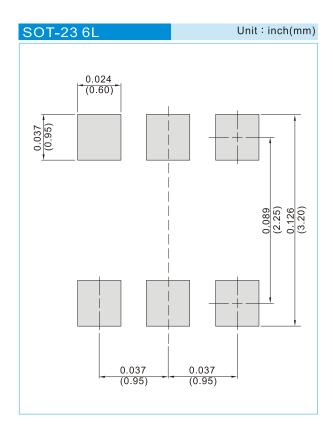




### PART NO. PACKING CODE VERSION

| Part No. Packing Code | Package Type | Packing Type       | Marking | Version                        |
|-----------------------|--------------|--------------------|---------|--------------------------------|
| PJS6809_S1_00001      | SOT-23 6L    | 3K pcs / 7" reel   | ST9     | Halogen free<br>RoHS compliant |
| PJS6809_S2_00001      | SOT-23 6L    | 10K pcs / 13" reel | ST9     | Halogen free<br>RoHS compliant |

#### **MOUNTING PAD LAYOUT**







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